



JCS630A

主要参数 MAIN CHARACTERISTICS

ID	9.0A
VDSS	200 V
Rdson-max (@Vgs=10V)	0.4Ω
Qg-typ	22nC

用途

- 高频开关电源
- 电子镇流器
- UPS 电源

产品特性

- 低栅极电荷
- 低 C_{RSS} (典型值 22pF)
- 开关速度快
- 产品全部经过雪崩测试
- 高抗 dv/dt 能力
- RoHS 产品

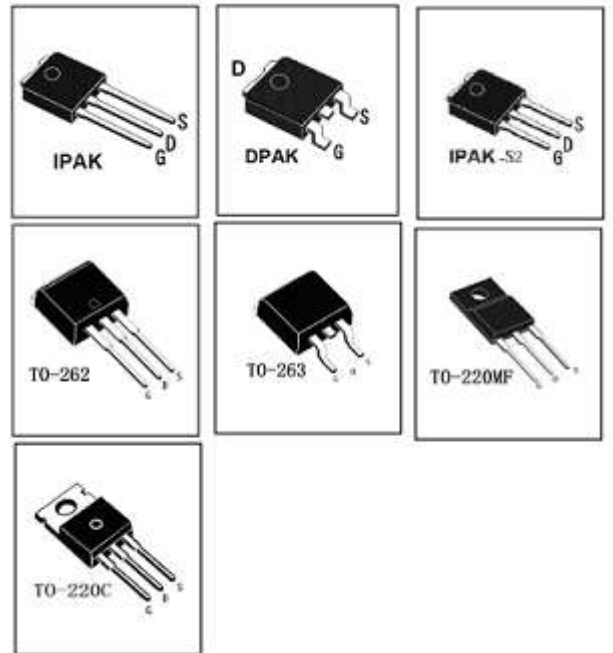
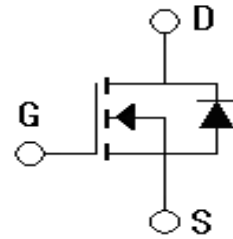
APPLICATIONS

- High efficiency switch mode power supplies
- Electronic lamp ballasts based on half bridge
- UPS

FEATURES

- Low gate charge
- Low C_{RSS} (typical 22pF)
- Fast switching
- 100% avalanche tested
- Improved dv/dt capability
- RoHS product

封装 Package



订货信息 ORDER MESSAGE

订货型号 Order codes				印 记 Marking	封 装 Package
有卤-条管 Halogen-Tube	无卤-条管 Halogen-Free-Tube	有卤-编带 Halogen-Reel	无卤-编带 Halogen-Free-Reel		
JCS630VA-V-B	JCS630VA-V-BR	N/A	N/A	JCS630VA	IPAK
JCS630RA-R-B	JCS630RA-R-BR	JCS630RA-R-A	JCS630RA-R-AR	JCS630RA	DPAK
JCS630VA-V2-B	JCS630VA-V2-BR	N/A	N/A	JCS630VA	IPAK-S2
JCS630BA-B-B	JCS630BA-B-BR	N/A	N/A	JCS630BA	T0-262
JCS630SA-S-B	JCS630SA-S-BR	JCS630SA-S-A	JCS630SA-S-AR	JCS630SA	T0-263
JCS630CA-C-B	JCS630CA-C-BR	N/A	N/A	JCS630CA	T0-220C
JCS630FA-F-B	JCS630FA-F-BR	N/A	N/A	JCS630FA	T0-220MF



绝对最大额定值 ABSOLUTE RATINGS ($T_C=25^{\circ}\text{C}$)

项 目 Parameter	符 号 Symbol	数 值 Value			单 位 Unit
		JCS630VA/RA	JCS630SA/BA/CA	JCS630FA	
最高漏极-源极直流电压 Drain-Source Voltage	V_{DSS}	200			V
连续漏极电流 Drain Current -continuous	I_D $T=25^{\circ}\text{C}$ $T=100^{\circ}\text{C}$	9.0		9.0*	A
		5.7		5.7*	A
最大脉冲漏极电流 (注 1) Drain Current -pulse (note 1)	I_{DM}	36		36*	A
最高栅源电压 Gate-Source Voltage	V_{GSS}	± 30			V
单脉冲雪崩能量 (注 2) Single Pulsed Avalanche Energy (note 2)	E_{AS}	162			mJ
雪崩电流 (注 1) Avalanche Current (note 1)	I_{AR}	9.0			A
重复雪崩能量 (注 1) Repetitive Avalanche Current (note 1)	E_{AR}	4.8	7.2	3.8	mJ
二极管反向恢复最大电压变化速率 (注 3) Peak Diode Recovery dv/dt (note 3)	dv/dt	5.5			V/ns
耗散功率 Power Dissipation	P_D $T_C=25^{\circ}\text{C}$ -Derate above 25°C	48	72	38	W
		0.39	0.57	0.3	W/ $^{\circ}\text{C}$
最高结温及存储温度 Operating and Storage Temperature Range	T_J, T_{STG}	-55~+150			$^{\circ}\text{C}$
引线最高焊接温度 Maximum Lead Temperature for Soldering Purposes	T_L	300			$^{\circ}\text{C}$

*漏极电流由最高结温限制

*Drain current limited by maximum junction temperature





电特性 ELECTRICAL CHARACTERISTIC

项 目 Parameter	符 号 Symbol	测试条件 Tests conditions	最小 Min	典型 Typ	最大 Max	单 位 Units
关态特性 Off –Characteristics						
漏—源击穿电压 Drain-Source Voltage	BV_{DSS}	$I_D=250\mu A, V_{GS}=0V$	200	-	-	V
击穿电压温度特性 Breakdown Voltage Temperature Coefficient	$\Delta BV_{DSS} / \Delta T_J$	$I_D=250\mu A$, referenced to $25^\circ C$	-	0.2	-	V/ $^\circ C$
零栅压下漏极漏电流 Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=200V, V_{GS}=0V, T_C=25^\circ C$	-	-	1	μA
		$V_{DS}=160V, T_C=125^\circ C$	-	-	10	μA
正向栅极体漏电流 Gate-body leakage current, forward	I_{GSSF}	$V_{DS}=0V, V_{GS}=30V$	-	-	100	nA
反向栅极体漏电流 Gate-body leakage current, reverse	I_{GSSR}	$V_{DS}=0V, V_{GS}=-30V$	-	-	-100	nA
通态特性 On-Characteristics						
阈值电压 Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D=250\mu A$	2.0	-	4.0	V
静态导通电阻 Static Drain-Source On-Resistance	$R_{DS(ON)}$	$V_{GS} = 10V, I_D=4.5A$	-	0.34	0.4	Ω
正向跨导 Forward Transconductance	g_{fs}	$V_{DS} = 40V, I_D=4.5A$ (note 4)	-	7.05	-	S
动态特性 Dynamic Characteristics						
输入电容 Input capacitance	C_{iss}	$V_{DS}=25V,$ $V_{GS}=0V,$ $f=1.0MHz$	-	550	720	pF
输出电容 Output capacitance	C_{oss}		-	85	110	pF
反向传输电容 Reverse transfer capacitance	C_{rss}		-	22	29	pF





电特性 ELECTRICAL CHARACTERISTICS

项 目 Parameter	符 号 Symbol	测试条件 Tests conditions	最小 Min	典型 Typ	最大 Max	单位 Units
开关特性 Switching –Characteristics						
延迟时间 Turn-On delay time	$t_{d(on)}$	$V_{DD}=100V, I_D=9.0A, R_G=25\Omega$ $V_{GS}=10V$ (note 4, 5)	-	11	30	ns
上升时间 Turn-On rise time	t_r		-	70	150	ns
延迟时间 Turn-Off delay time	$t_{d(off)}$		-	60	130	ns
下降时间 Turn-Off Fall time	t_f		-	65	140	ns
栅极电荷总量 Total Gate Charge	Q_g	$V_{DS}=160V,$ $I_D=9.0A$ $V_{GS}=10V$ (note 4, 5)	-	22	29	nC
栅—源电荷 Gate-Source charge	Q_{gs}		-	3.6	-	nC
栅—漏电荷 Gate-Drain charge	Q_{gd}		-	10.2	-	nC
漏—源二极管特性及最大额定值 Drain-Source Diode Characteristics and Maximum Ratings						
正向最大连续电流 Maximum Continuous Drain-Source Diode Forward Current		I_S	-	-	9.0	A
正向最大脉冲电流 Maximum Pulsed Drain-Source Diode Forward Current		I_{SM}	-	-	36	A
正向最大连续电流 Maximum Continuous Drain-Source Diode Forward Current	V_{SD}	$V_{GS}=0V, I_S=9.0A$	-		1.5	V
反向恢复时间 Reverse recovery time	t_{rr}	$V_{GS}=0V, I_S=9.0A$ $di_F/dt=100A/\mu s$ (note 4)		140		ns
反向恢复电荷 Reverse recovery charge	Q_{rr}			0.87		μC

热特性 THERMAL CHARACTERISTIC

项 目 Parameter	符 号 Symbol	最大值 Value			单 位 Unit
		JCS630VA/ RA	JCS630SA/ BA/CA	JCS630FA	
结到管壳的热阻 Thermal Resistance, Junction to Case	$R_{th(j-c)}$	2.58	1.74	3.33	$^{\circ}C/W$
结到环境的热阻 Thermal Resistance, Junction to Ambient	$R_{th(j-A)}$	62.5			$^{\circ}C/W$

注:

- 1: 脉冲宽度由最高结温限制
- 2: $L=4mH, I_{AS}=9.0A, V_{DD}=50V, R_G=25\Omega$, 起始结温 $T_J=25^{\circ}C$
- 3: $I_{SD} \leq 9.0A, di/dt \leq 200A/\mu s, V_{DD} \leq BV_{DSS}$, 起始结温 $T_J=25^{\circ}C$
- 4: 脉冲测试: 脉冲宽度 $\leq 300\mu s$, 占空比 $\leq 2\%$
- 5: 基本与工作温度无关

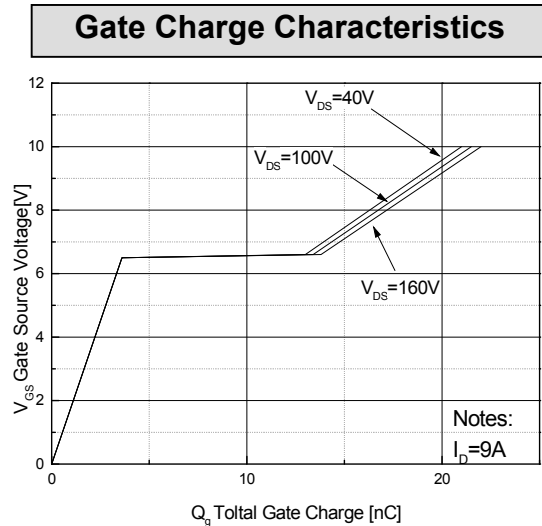
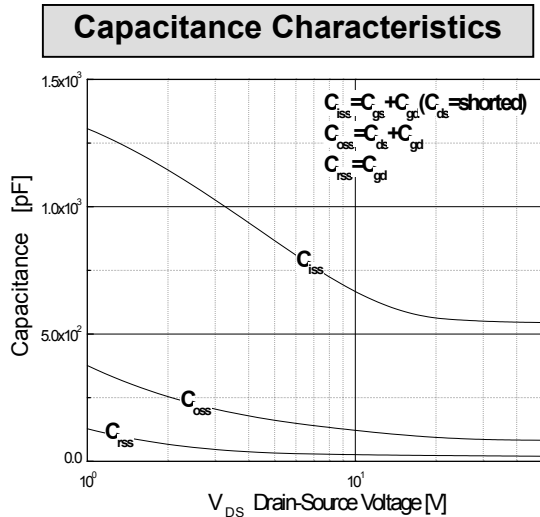
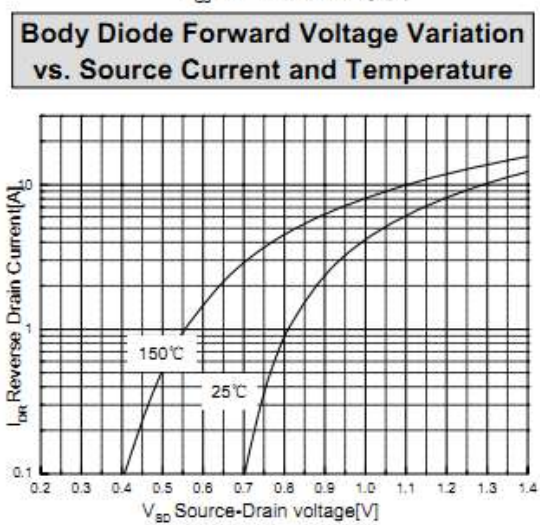
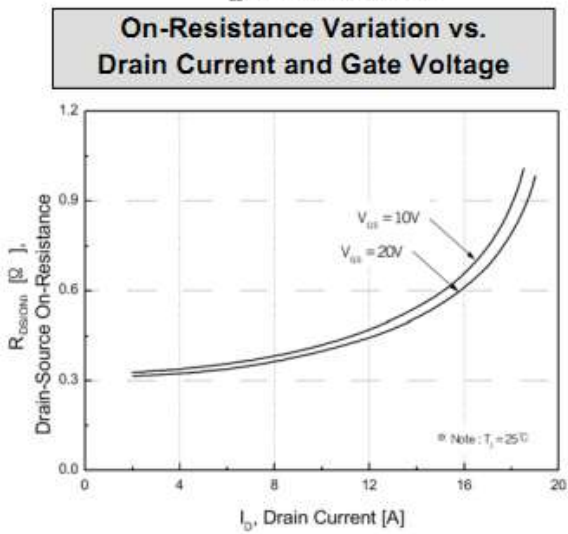
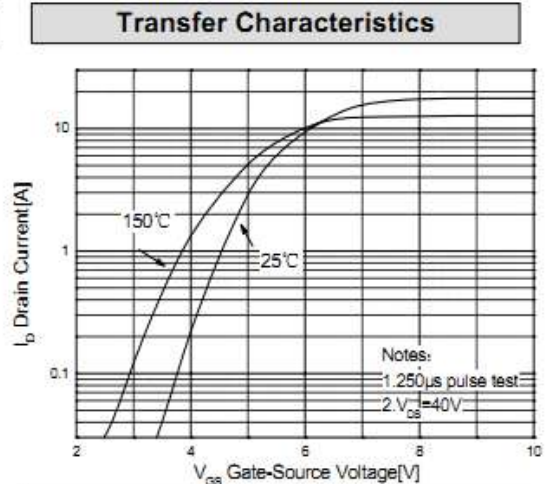
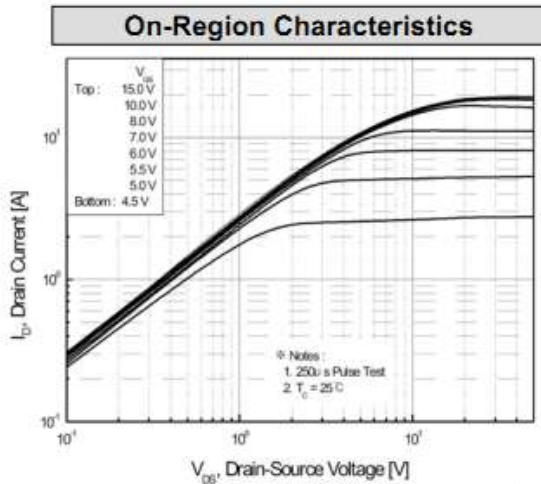
Notes:

- 1: Pulse width limited by maximum junction temperature
- 2: $L=4mH, I_{AS}=9.0A, V_{DD}=50V, R_G=25\Omega$, Starting $T_J=25^{\circ}C$
- 3: $I_{SD} \leq 9.0A, di/dt \leq 200A/\mu s, V_{DD} \leq BV_{DSS}$, Starting $T_J=25^{\circ}C$
- 4: Pulse Test: Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$
- 5: Essentially independent of operating temperature





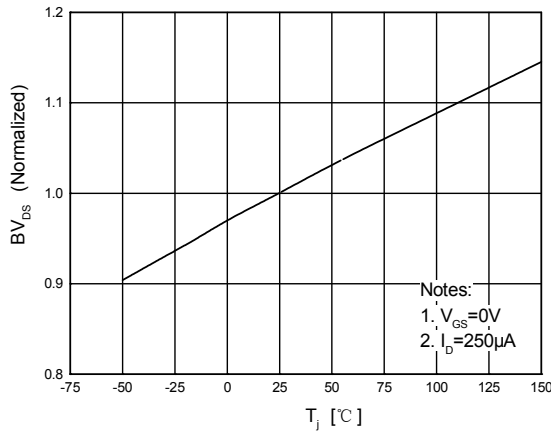
特征曲线 ELECTRICAL CHARACTERISTICS (curves)



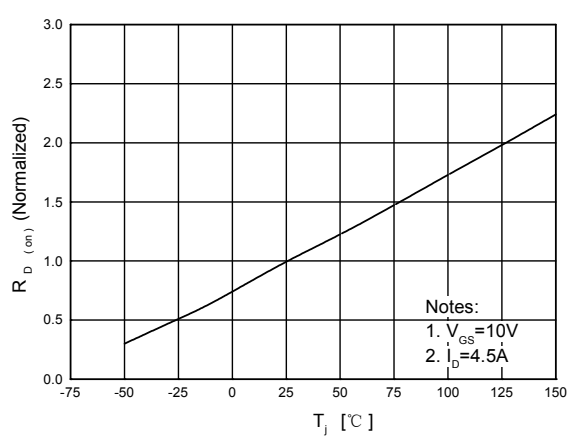


特征曲线 ELECTRICAL CHARACTERISTICS (curves)

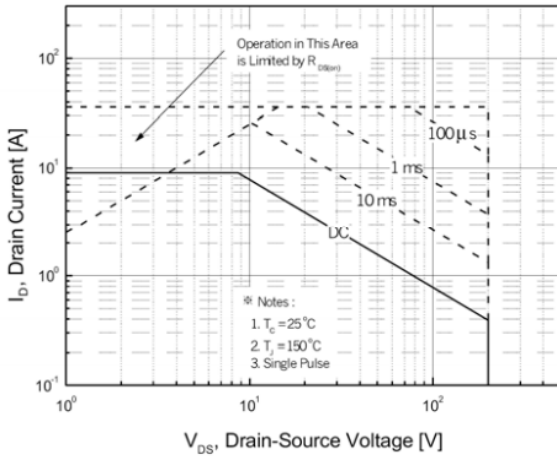
Breakdown Voltage Variation vs. Temperature



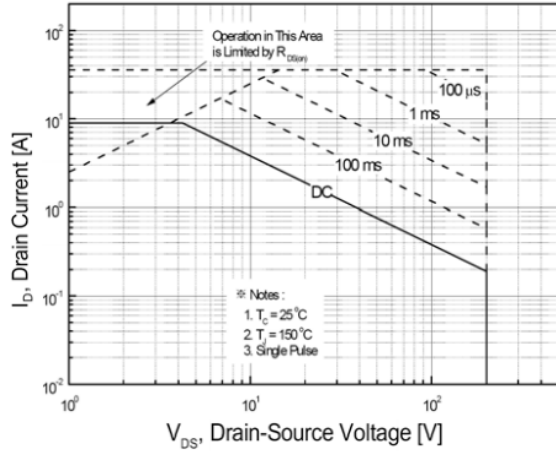
On-Resistance Variation vs. Temperature



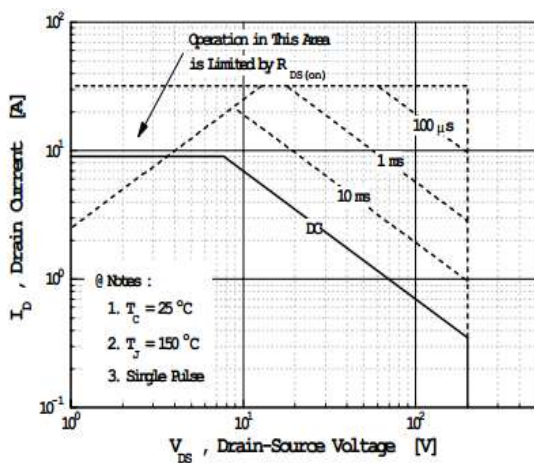
Maximum Safe Operating Area For JCS630SA/BA/CA



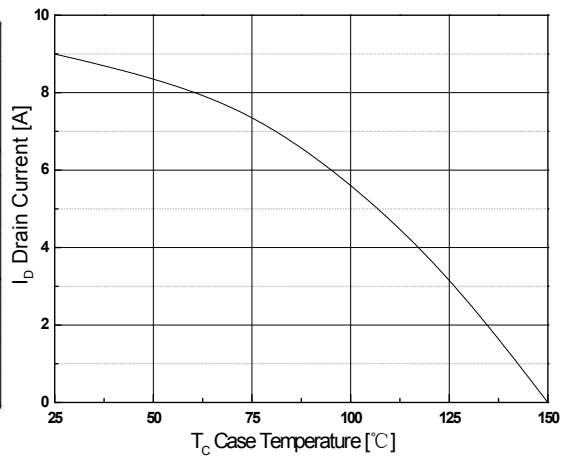
Maximum Safe Operating Area For JCS630FA



Maximum Safe Operating Area For JCS630VA/RA

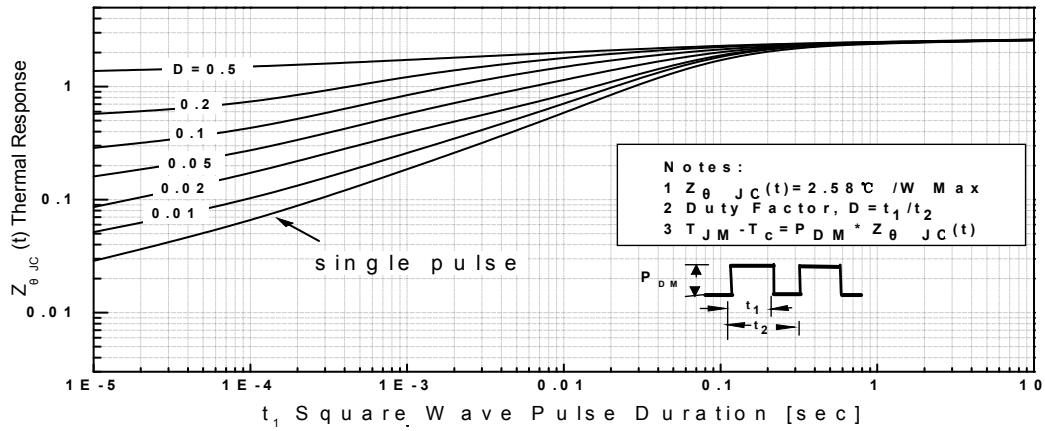


Maximum Drain Current vs. Case Temperature

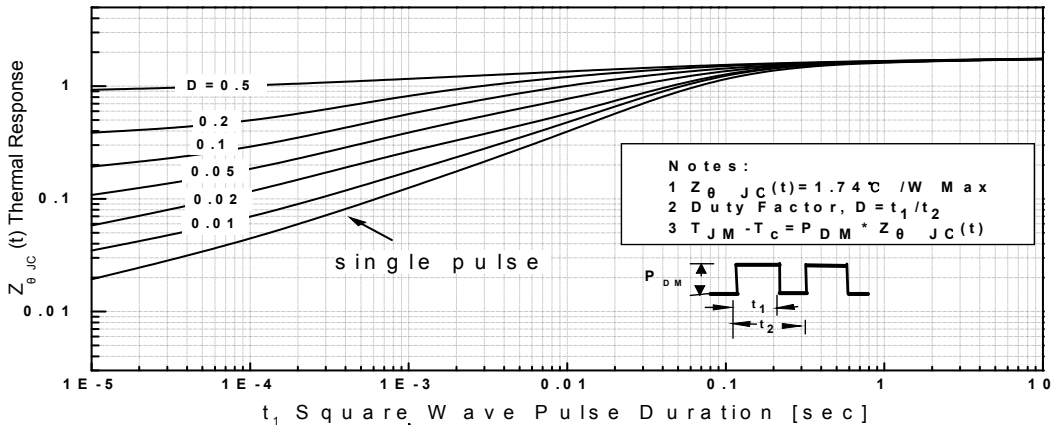




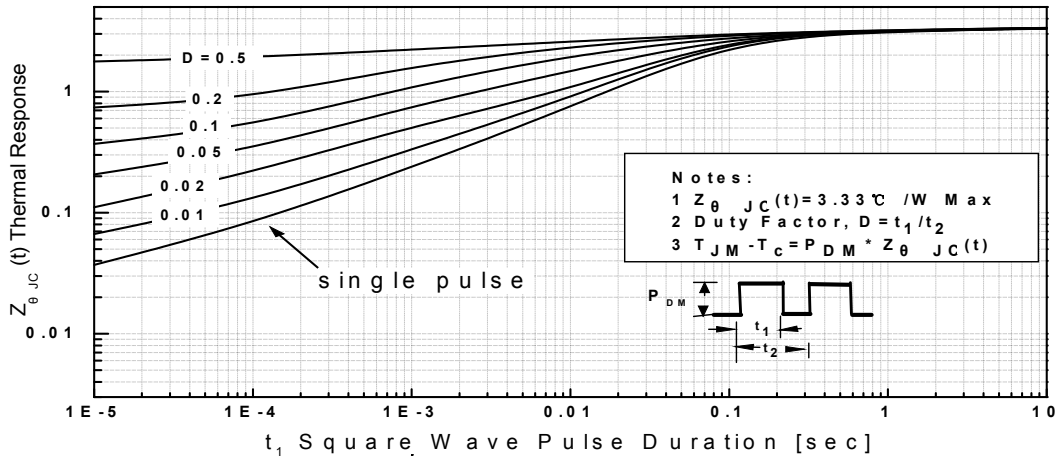
Transient Thermal Response Curve For JCS630VA/RA



Transient Thermal Response Curve For JCS630SA/BA/CA



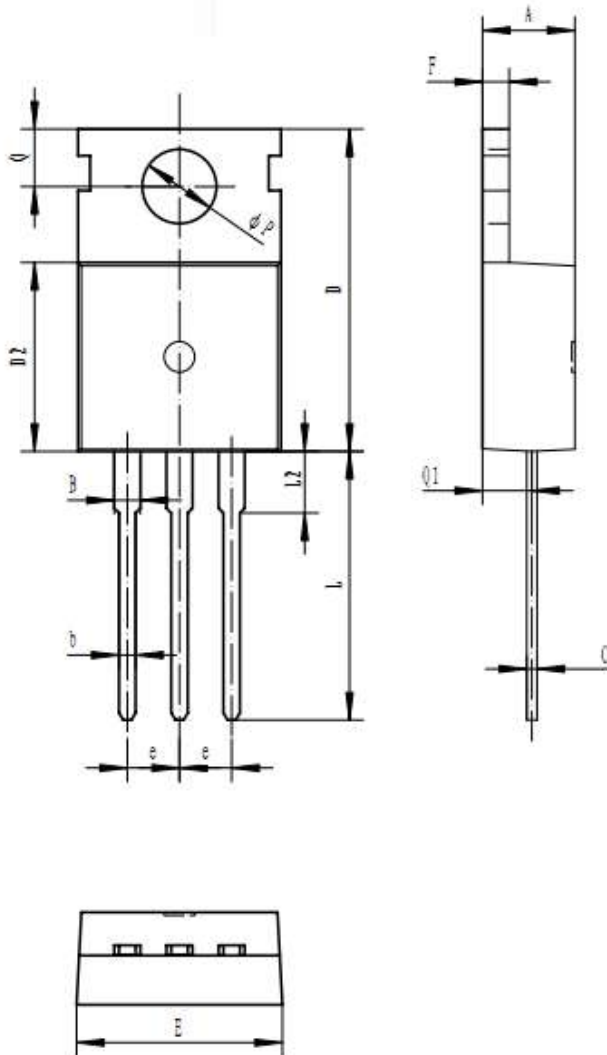
Transient Thermal Response Curve For JCS630FA





TO-220C

单位 Unit: mm



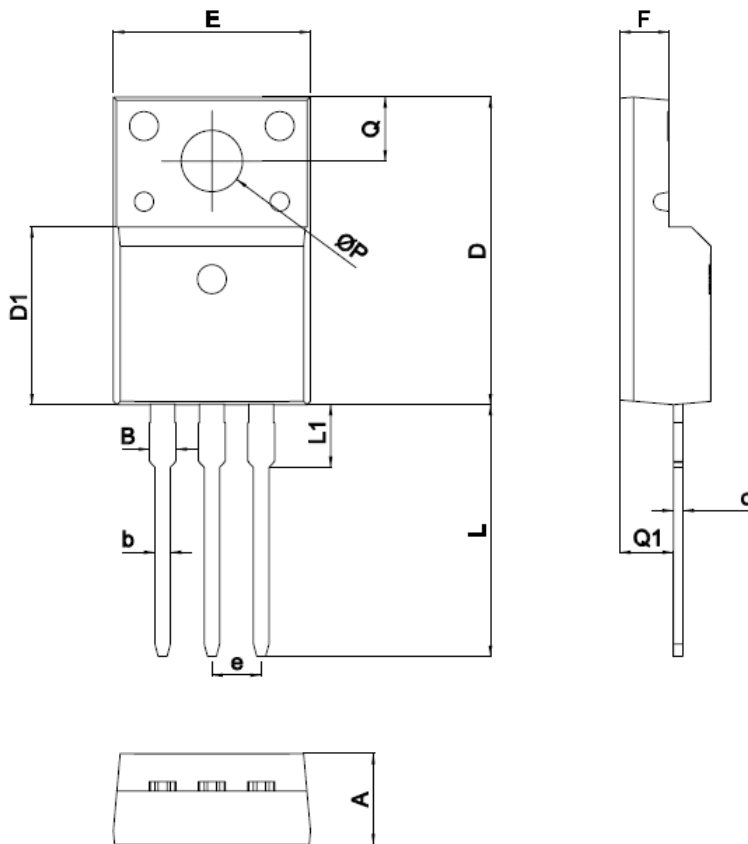
符号 symbol	MIN	MAX
A	4.30	4.70
B	1.22	1.40
b	0.70	0.95
c	0.40	0.65
D	15.20	16.20
D2	9.00	9.40
E	9.70	10.10
e	2.39	2.69
F	1.25	1.40
L	12.60	13.60
L2	2.80	3.20
Q	2.60	3.00
Q1	2.20	2.60
P	3.50	3.80





TO-220MF

单位 Unit: mm



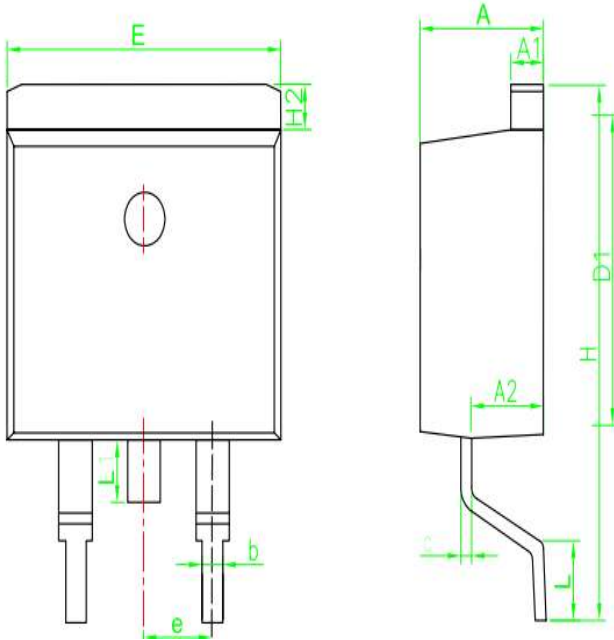
SYMBOL	mm	
	MIN	MAX
A	4.5	4.9
B		1.47
b	0.7	0.9
c	0.45	0.60
D	15.67	16.07
D1	9.04	9.20
e	2.54TYPE	
E	9.96	10.36
F	2.34	2.74
L	12.58	13.38
L1	3.13	3.33
Q	3.2	3.4
Q1	2.56	2.96
ΦP	3.08	3.28





TO-263

单位 Unit: mm



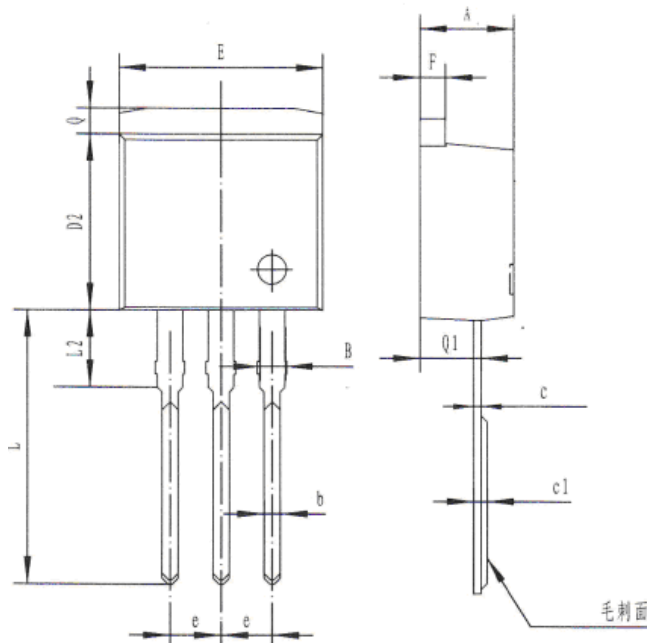
SYMBOL	MM	
	MIN	MAX
A	4.30	4.80
A1	1.12	1.42
A2	2.54	2.84
b	0.67	1.00
c	0.29	0.52
D1	8.40	9.00
E	9.80	10.46
e	2.54BSC	
H	14.00	16.00
H2	1.12	1.45
L	1.50	3.10
L1	1.45	1.70



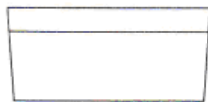


TO-262

单位 Unit: mm



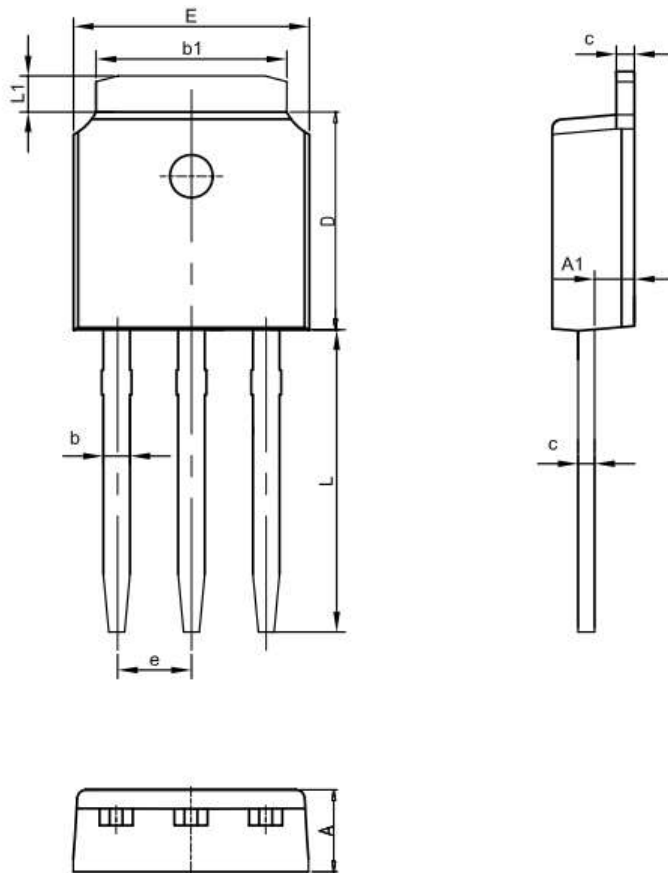
符号 symbol	MIN	MAX
A	4.40	4.90
B	1.10	1.40
b	0.70	0.95
c	0.30	0.60
c1	0.33	0.63
D2	8.20	9.20
E	9.60	10.50
e	2.39	2.69
F	1.20	1.35
L	13.11	14.61
L2	3.55	4.05
Q	1.10	1.40
Q1	2.65	2.85





IPAK

单位 Unit: mm



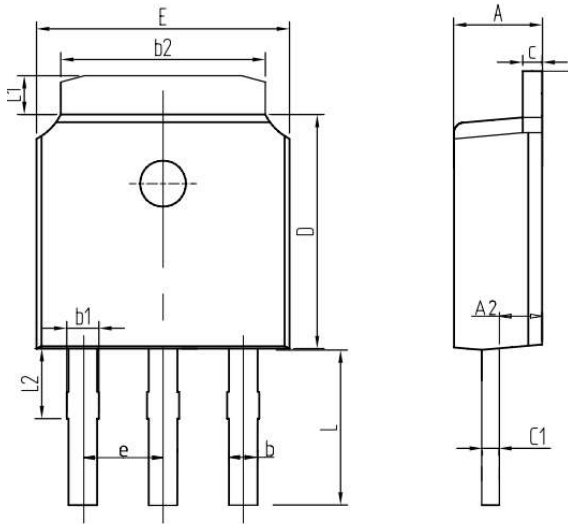
SYMBOL	MM	
	MIN	MAX
A	2.1	2.5
A1	0.87	1.27
b	0.63	0.93
b1	5.13	5.53
c	0.40	0.60
D	5.80	6.40
E	6.30	6.90
L	9.10	9.70
e	2.286BSC	
L1	0.82	1.22





IPAK-S2

单位 Unit: mm



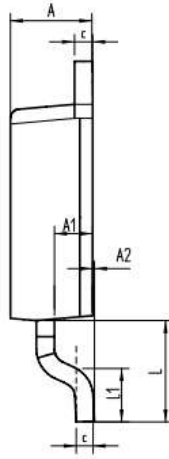
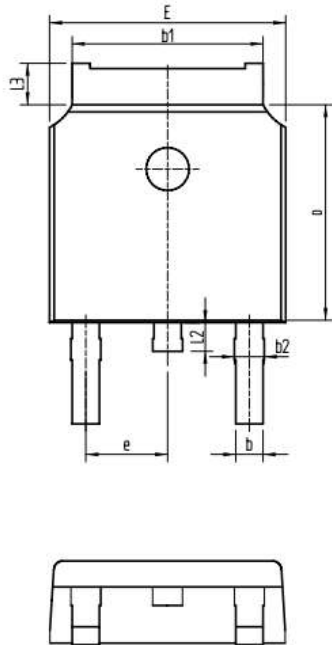
SYMBOL	MM	
	MIN	MAX
A	2.15	2.45
A2	0.92	1.22
b	0.68	0.88
b1	0.61	0.95
b2	5.18	5.48
c	0.43	0.63
c1	0.41	0.61
D	5.95	6.25
E	6.45	6.75
e	2.286BSC	
L	3.35	3.65
L1	0.82	1.22
L2	0.90	1.20





DPAK

单位 Unit: mm



SYMBOL	mm	
	MIN	MAX
A	2.16	2.41
A1	0.97	1.17
A2	0.00	0.15
b	0.63	0.93
b1	5.13	5.53
b2	0.66	0.96
c	0.40	0.60
D	5.80	6.40
E	6.30	6.90
e	2.286BSC	
L	2.50	3.30
L1	1.20	1.80
L2	0.60	1.00
L3	0.85	1.30





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- 3.在电路设计时请不要超过器件的绝对最大额定值，否则会影响整机的可靠性。
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3. Please do not exceed the absolute maximum ratings of the device when circuit designing.
4. Jilin Sino-microelectronics co., Ltd reserves the right to make changes in this specification sheet and is subject to change without prior notice.

联系方式

吉林华微电子股份有限公司

公司地址：吉林省吉林市深圳街 99 号

邮编：132013

总机：86-432-64678411

传真：86-432-64665812

网址：www.hwdz.com.cn

市场营销部

地址：吉林省吉林市深圳街 99 号

邮编：132013

电话： 86-432-64675588

64675688

64678411

传真：86-432-64671533

CONTACT

JILIN SINO-MICROELECTRONICS CO., LTD.

ADD: No.99 Shenzhen Street, Jilin City, Jilin Province, China.

Post Code: 132013

Tel: 86-432-64678411

Fax: 86-432-64665812

Web Site: www.hwdz.com.cn

MARKET DEPARTMENT

ADD: No.99 Shenzhen Street, Jilin City, Jilin Province, China.

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